



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

NPN Epitaxial Planar Silicon Transistor

2SC5374A — VHF to UHF Band OSC, High-Frequency Amplifier Applications

Features

- High gain : $|S_{21e}|^2 = 10.5\text{dB typ (f=1GHz)}$
- High cut-off frequency : $f_T = 5.2\text{GHz typ}$

Specifications

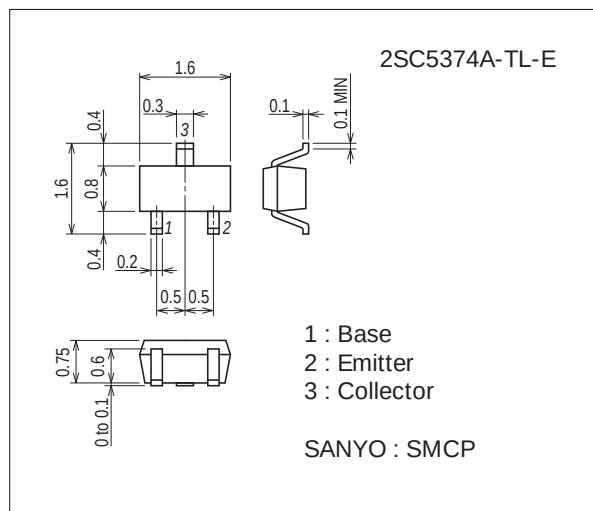
Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		20	V
Collector-to-Emitter Voltage	V_{CEO}		10	V
Emitter-to-Base Voltage	V_{EBO}		2	V
Collector Current	I_C		100	mA
Collector Dissipation	P_C		100	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Package Dimensions

unit : mm (typ)

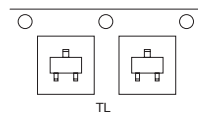
7027A-002



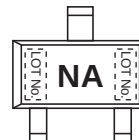
Product & Package Information

- Package : SMCP
- JEITA, JEDEC : SC-75, SOT-416
- Minimum Packing Quantity : 3,000 pcs./reel

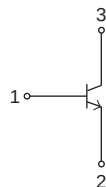
Packing Type: TL



Marking



Electrical Connection



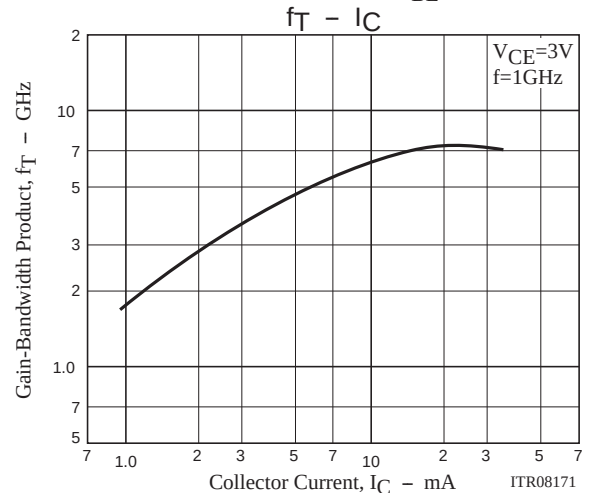
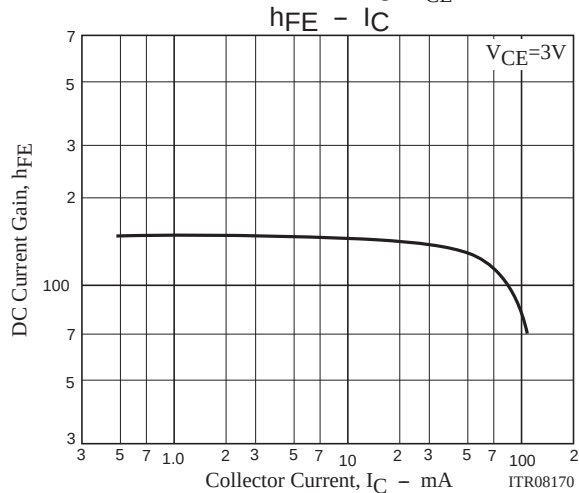
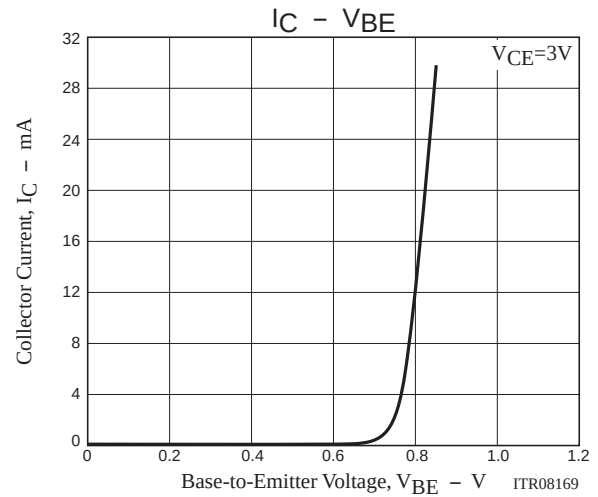
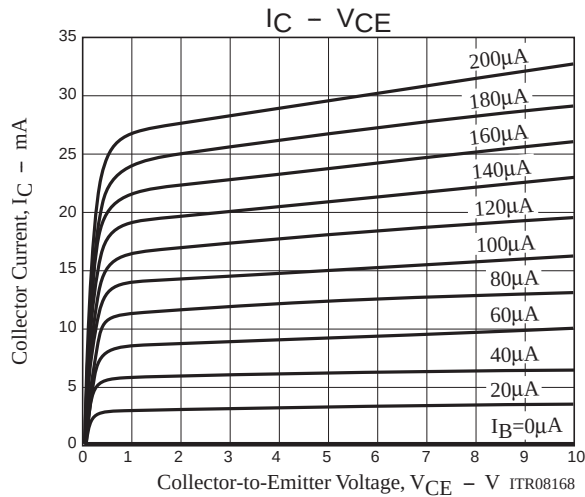
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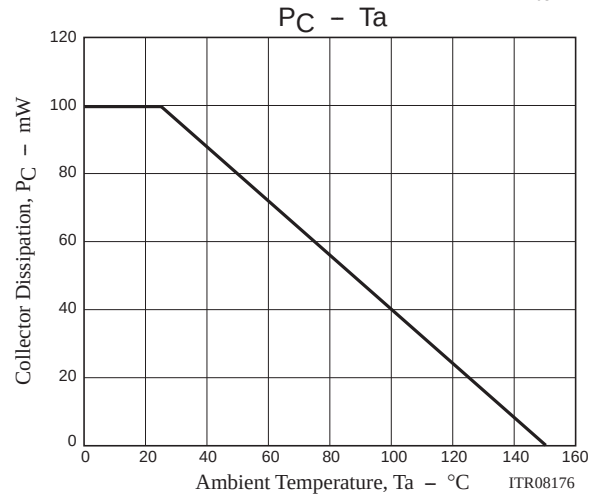
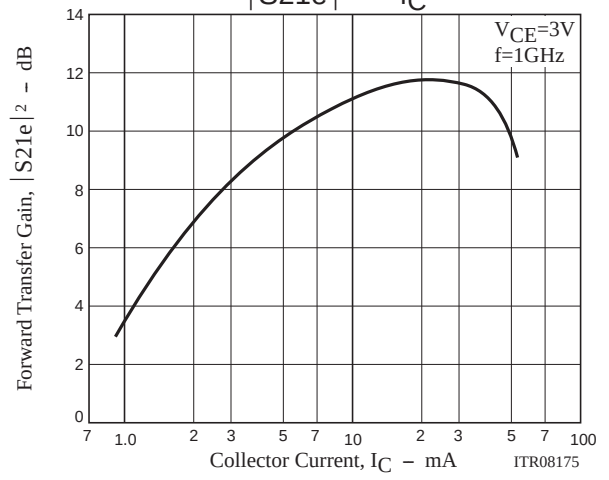
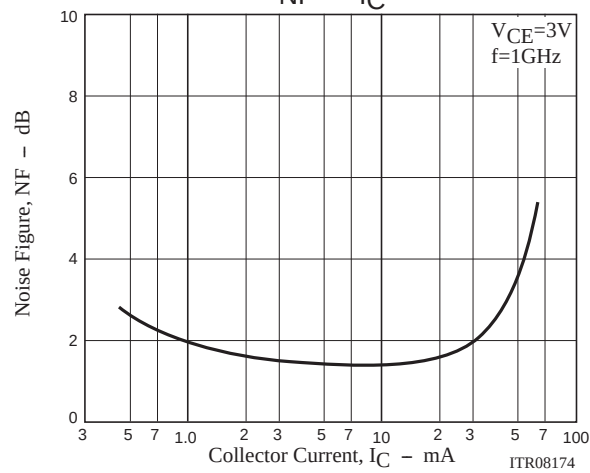
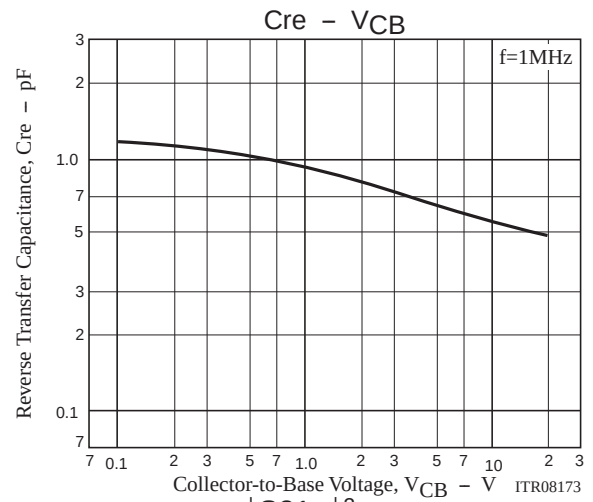
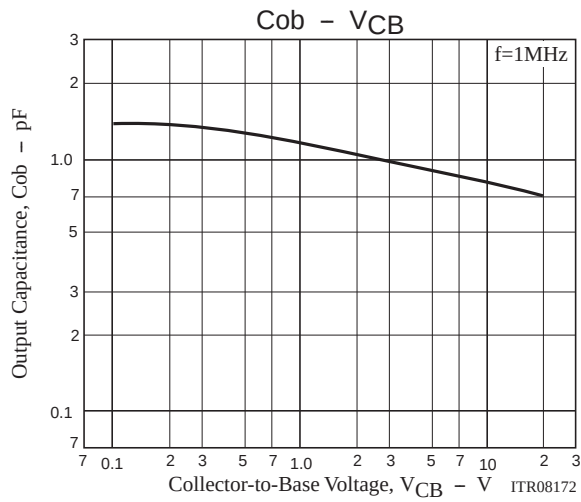
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=10V, I_E=0A$			1.0	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=1V, I_C=0A$			10	μA
DC Current Gain	h_{FE1}	$V_{CE}=3V, I_C=7mA$	110		180	
	h_{FE2}	$V_{CE}=3V, I_C=30mA$	100			
Gain-Bandwidth Product	f_T	$V_{CE}=3V, I_C=7mA$	3	5.2		GHz
Output Capacitance	C_{ob}	$V_{CB}=3V, f=1MHz$		1.0	1.5	pF
Reverse Transfer Capacitance	C_{re}			0.7		pF
Forward Transfer Gain	$ S_{21e} ^2$	$V_{CE}=3V, I_C=7mA, f=1GHz$	8	10.5		dB
Noise Figure	NF	$V_{CE}=3V, I_C=7mA, f=1GHz$		1.4	2.5	dB

Ordering Information

Device	Package	Shipping	memo
2SC5374A-TL-E	SMCP	3,000pcs./reel	Pb Free



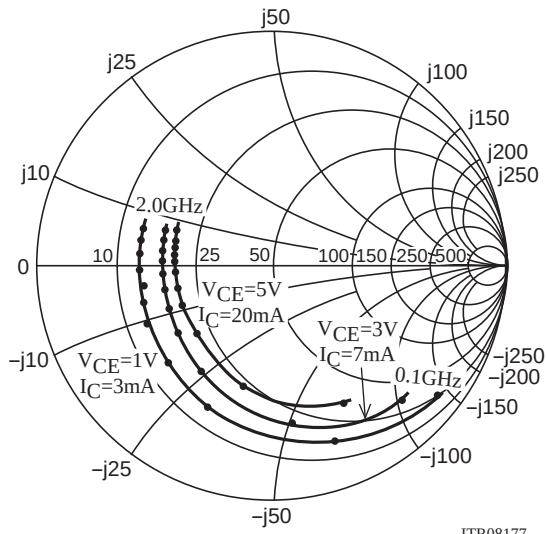


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S Parameter

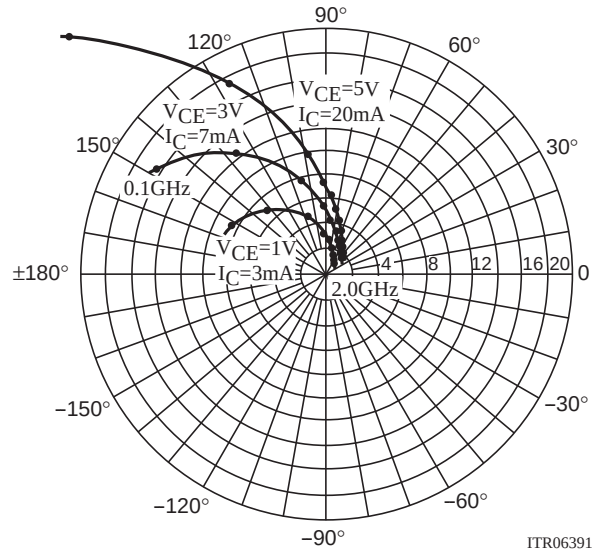
S11e

f=100MHz, 200MHz to 2000MHz(200MHz Step)



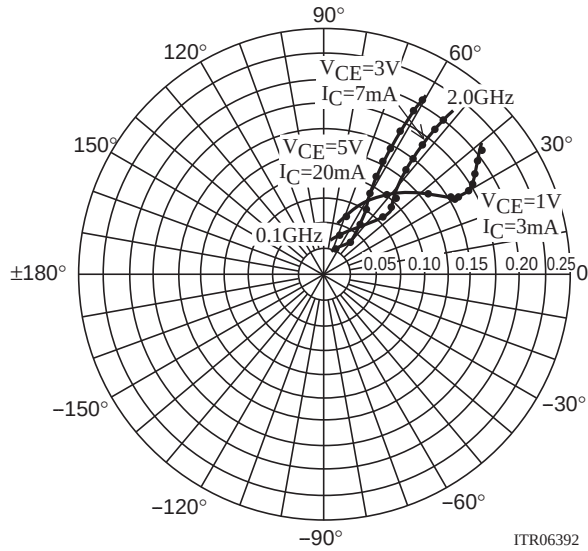
S21e

f=100MHz, 200MHz to 2000MHz(200MHz Step)



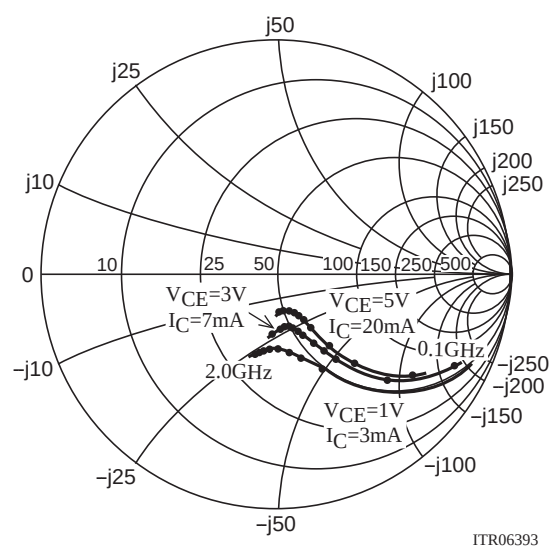
S12e

f=100MHz, 200MHz to 2000MHz(200MHz Step)



S22e

f=100MHz, 200MHz to 2000MHz(200MHz Step)



2SC5374A

S Parameters (Common emitter)

$V_{CE}=1V$, $I_C=3mA$, $Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.875	-40.6	8.627	152.3	0.062	67.9	0.918	-23.4
200	0.785	-71.6	6.874	132.5	0.101	52.1	0.748	-41.7
400	0.651	-114.8	4.701	107.3	0.135	37.1	0.537	-57.6
600	0.613	-136.9	3.365	92.8	0.152	31.1	0.430	-65.6
800	0.581	-153.9	2.716	81.9	0.155	29.9	0.361	-74.3
1000	0.568	-164.2	2.218	73.4	0.161	30.0	0.326	-80.2
1200	0.556	-172.0	1.863	66.2	0.170	30.5	0.300	-86.1
1400	0.563	-178.1	1.626	59.6	0.177	32.7	0.297	-92.3
1600	0.558	175.4	1.473	53.9	0.185	35.4	0.306	-96.5
1800	0.560	168.9	1.345	48.1	0.196	37.4	0.313	-100.6
2000	0.567	163.1	1.230	42.5	0.205	38.0	0.335	-102.9

$V_{CE}=3V$, $I_C=7mA$, $Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.789	-48.3	16.232	147.7	0.039	66.1	0.862	-27.2
200	0.670	-83.7	12.431	126.4	0.061	53.0	0.673	-44.6
400	0.552	-123.8	7.607	104.7	0.081	45.2	0.438	-59.1
600	0.522	-145.3	5.401	92.7	0.094	45.9	0.333	-65.1
800	0.504	-158.5	4.155	84.1	0.106	48.2	0.290	-68.7
1000	0.488	-169.1	3.425	77.1	0.121	49.1	0.270	-71.0
1200	0.478	-176.1	2.849	71.0	0.136	51.0	0.253	-74.7
1400	0.481	178.4	2.511	65.6	0.152	52.2	0.239	-79.6
1600	0.478	172.7	2.237	60.7	0.167	52.8	0.240	-82.8
1800	0.492	167.4	2.016	55.5	0.185	53.2	0.245	-86.7
2000	0.489	162.0	1.844	50.5	0.200	52.7	0.248	-90.0

$V_{CE}=5V$, $I_C=20mA$, $Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.643	-66.4	26.381	137.4	0.029	62.8	0.748	-36.3
200	0.530	-104.6	17.543	116.5	0.041	54.2	0.531	-52.5
400	0.459	-140.3	9.835	98.9	0.058	55.4	0.322	-62.7
600	0.447	-157.2	6.805	89.4	0.074	59.2	0.246	-65.5
800	0.440	-168.4	5.210	82.4	0.092	61.4	0.213	-68.6
1000	0.434	-175.9	4.194	76.6	0.110	61.9	0.199	-70.2
1200	0.437	177.1	3.518	71.5	0.129	62.3	0.191	-72.9
1400	0.437	173.0	3.077	66.7	0.148	61.8	0.184	-76.5
1600	0.438	168.4	2.730	62.5	0.166	61.6	0.181	-80.9
1800	0.439	164.2	2.459	58.0	0.186	60.7	0.186	-84.8
2000	0.444	159.1	2.249	53.5	0.203	59.5	0.192	-87.3

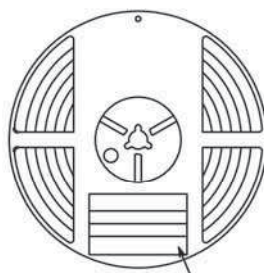
Embossed Taping Specification

2SC5374A-TL-E

1. Packing Format

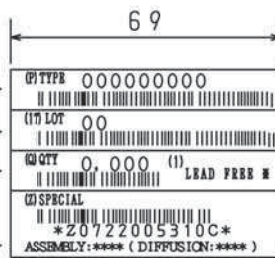
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
SMCP	SMCP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



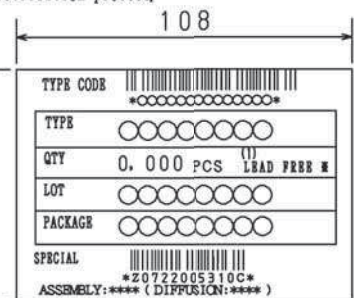
Reel label

Type No.
LOT No.
Quantity
Origin

Reel label, Inner box label
(unit:mm)

Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical
distribution process.



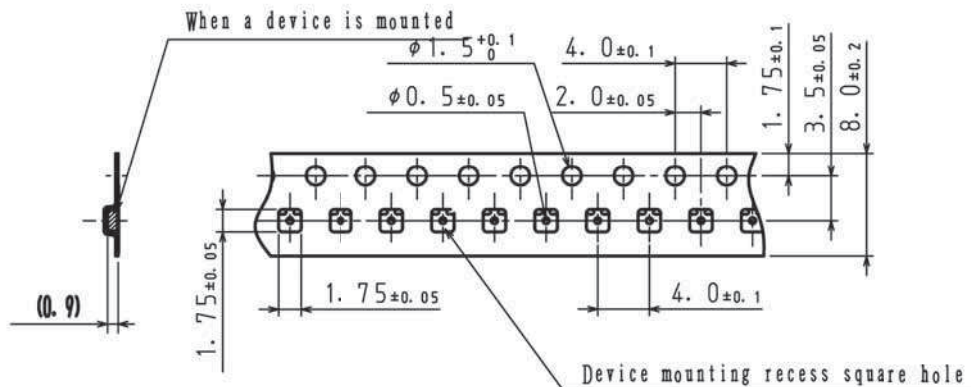
NOTE (1)

The LEAD FREE * description shows that the surface
treatment of the terminal is lead free.

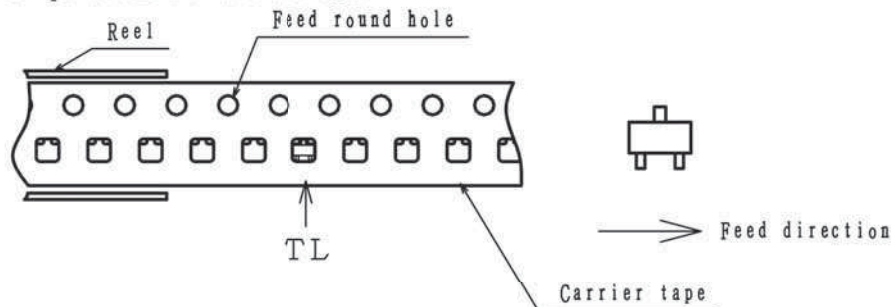
Label	JEITA Phase
.....	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)

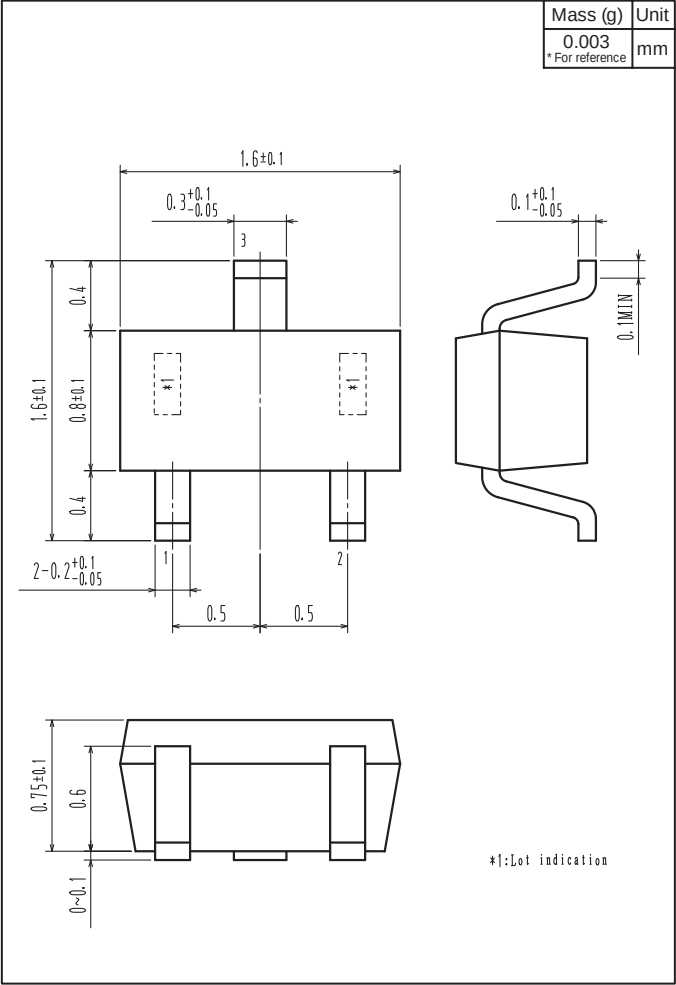


2-2. Device placement direction

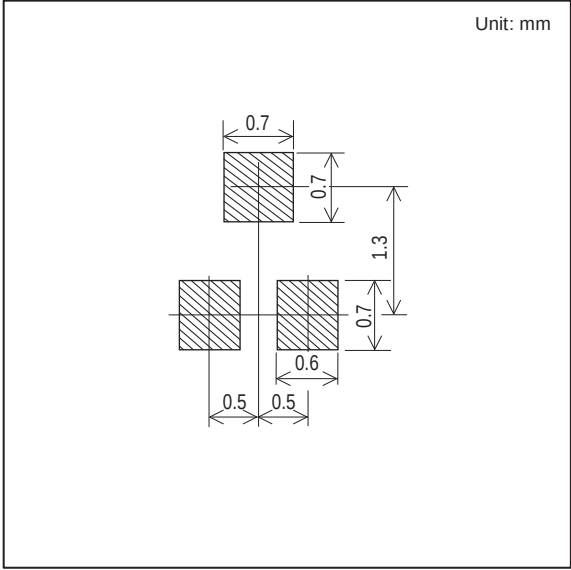


Those with one electrode terminal on the feed hole side.....TL

Outline Drawing
2SC5374A-TL-E



Land Pattern Example



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